

HIGH EFFICIENCY
 FAST RECOVERY DIODES

MAIN PRODUCT CHARACTERISTICS

I _{F(AV)}	8 A
V _{RRM}	200 V
t _{rr}	35 ns
V _F	0.85 V

FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIMES
- HIGH SURGE CURRENT
- HIGH DISSIPATION MINIATURE PACKAGE
- SURFACE MOUNT TECHNOLOGY COMPATIBLE

DESCRIPTION

Single rectifier suited for switchmode power supply and high frequency DC to DC converters.

Packaged in a high performance surface mount package PSO-10, this device is intended for use in high frequency inverters, free wheeling and polarity protection applications.


ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{RRM}	Repetitive peak reverse voltage	200	V
I _{F(RMS)}	RMS forward current (All pins connected)	17	A
I _{F(AV)}	Average forward current	8	A
I _{FSM}	Surge non repetitive forward current (All pins connected)	80	A
I _{FRM}	Repetitive peak forward current	75	A
T _{stg} T _j	Storage and junction temperature range	- 40 to + 150	°C

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case thermal resistance	2.8	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I _R *	Reverse leakage current	V _R = V _{RRM}	T _j = 25°C			10	μA
			T _j = 100°C			0.6	mA
V _F **	Forward voltage drop	I _F = 5 A	T _j = 125°C			0.85	V
		I _F = 10 A	T _j = 125°C			1.05	
		I _F = 10 A	T _j = 25°C			1.15	

Pulse test : * tp = 5 ms, duty cycle < 2 %

** tp = 380 μs, duty cycle < 2 %

To evaluate the conduction losses use the following equation :

$$P = 0.65 \times I_{F(AV)} + 0.040 I_{F}^2(RMS)$$

RECOVERY CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25°C I _{rr} = 0.25 A	I _F = 0.5A I _R = 1A			25	ns
		T _j = 25°C dI _F /dt = -50A/μs	I _F = 1A V _R = 30V			35	
t _f	Forward recovery time	T _j = 25°C dI _F /dt = 100A/μs V _{FR} = 1.1 x V _F max	I _F = 1A		15		ns
V _{FP}	Peak forward voltage	T _j = 25°C dI _F /dt = 100A/μs	I _F = 1A			2	V

PIN OUT configuration in PowerSO-10 :

Anode = pin 1 to 5

Cathode = connected to base tab

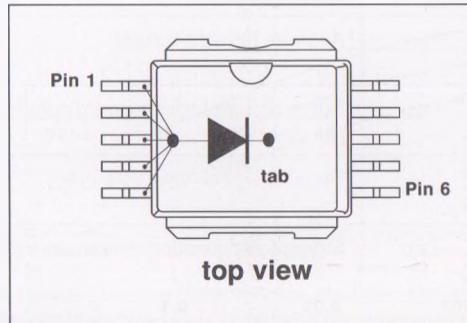


Fig.1 : Average forward power dissipation versus average forward current.

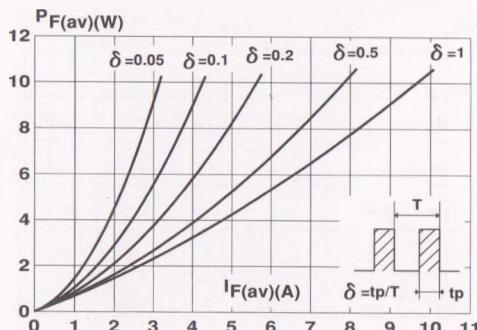


Fig.3 : Forward voltage drop versus forward current (maximum values).

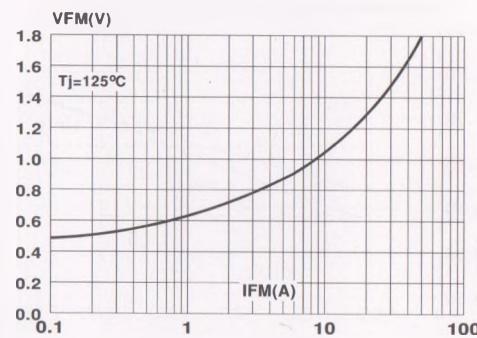


Fig.5 : Non repetitive surge peak forward current versus overload duration.

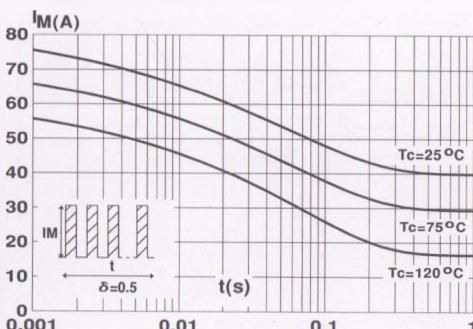


Fig.2 : Peak current versus form factor.

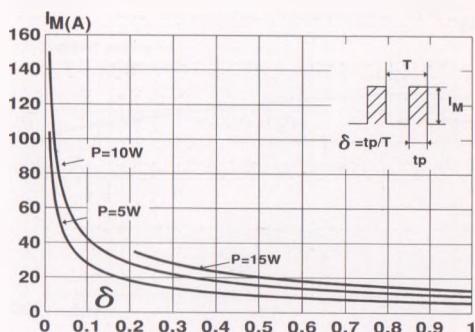


Fig.4 : Relative variation of thermal impedance junction to case versus pulse duration.

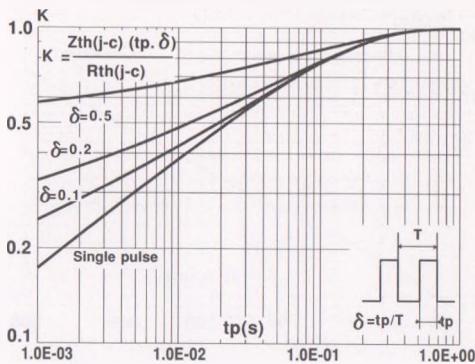


Fig.6 : Average current versus ambient temperature. (duty cycle : 0.5)

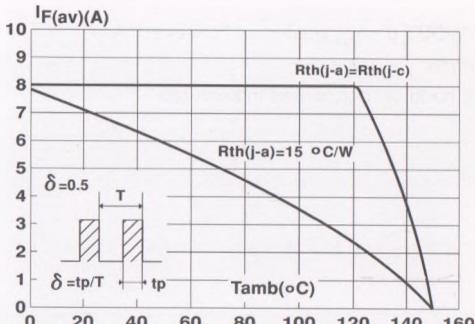


Fig.7 : Junction capacitance versus reverse voltage applied (Typical values).

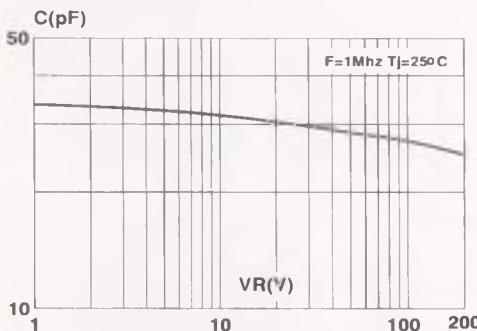


Fig.9 : Peak reverse current versus dIF/dt.

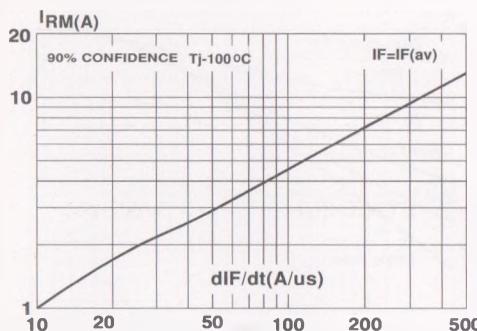


Fig.8 : Recovery charges versus dIF/dt.

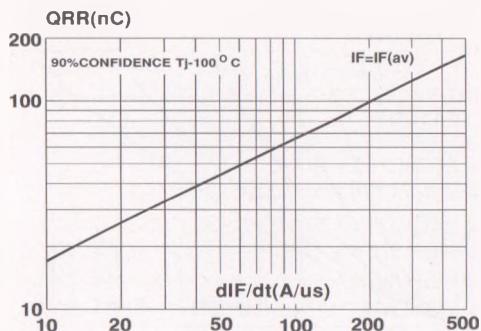


Fig.10 : Dynamic parameters versus junction temperature.

